

Product data sheet

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a leadless medium power DFN2020MD-6 (SOT1220) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Extended temperature range T_i = 175 °C
- Small and leadless ultra thin SMD plastic package: 2 x 2 x 0.65 mm
- Tin-plated 100% solderable side pads for optical solder inspection
- ElectroStatic Discharge (ESD) protection > 1.5 kV HBM
- Trench MOSFET technology
- AEC-Q101 qualified

3. Applications

- Relay driver
- High-speed line driver
- Low-side loadswitch
- Switching circuits

4. Quick reference data

Table 1. Quick I	reference data						
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	30	V
V _{GS}	gate-source voltage			-12	-	12	V
I _D	drain current	V_{GS} = 4.5 V; T_{amb} = 25 °C	[1]	-	-	3.8	А
Static characteristics							
R _{DSon}	drain-source on-state resistance	V _{GS} = 4.5 V; I _D = 3.8 A; T _j = 25 °C		-	55	72	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

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5. Pinning information

Table 2.	Pinning in	formation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	D	drain		D
2	D	drain		
3	G	gate		G ← → ☆ ↓
4	S	source		
5	D	drain	Transparent top view	
6	D	drain	DFN2020MD-6 (SOT1220)	' S
7	D	drain		017aaa255
8	S	source		

6. Ordering information

Table 3. Ordering information

Type number	Package	age				
	Name	Description	Version			
PMPB55XNEA	DFN2020MD-6	DFN2020MD-6: plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals	SOT1220			

7. Marking

Table 4. Marking codes	
Type number	Marking code
PMPB55XNEA	3Q

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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	30	V
V _{GS}	gate-source voltage			-12	12	V
I _D	drain current	V _{GS} = 4.5 V; T _{amb} = 25 °C	[1]	-	3.8	А
		V _{GS} = 4.5 V; T _{amb} = 100 °C	[1]	-	2.4	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	16	А
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	$T_{j(init)}$ = 25 °C; I _D = 0.3 A; DUT in avalanche (unclamped)		-	6.2	mJ
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	550	mW
			[1]	-	1.95	W
		T _{sp} = 25 °C		-	10	W
Tj	junction temperature			-55	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C
Source-drai	n diode					
I _S	source current	T _{amb} = 25 °C	[1]	-	1.9	А
ESD maxim	um rating					
V _{ESD}	electrostatic discharge voltage	НВМ	[3]	-	1500	V

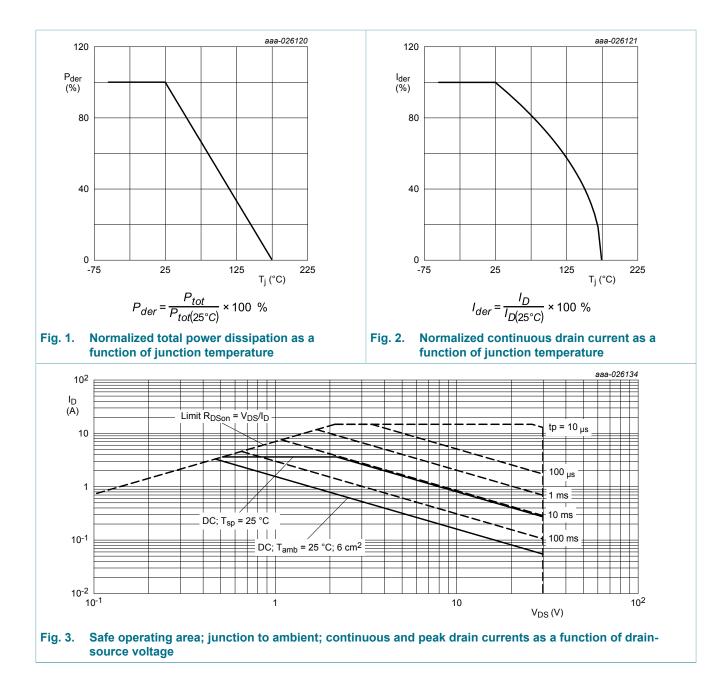
Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm². [1]

Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper; tin-plated and standard footprint. Measures between all pins.

[2] [3]

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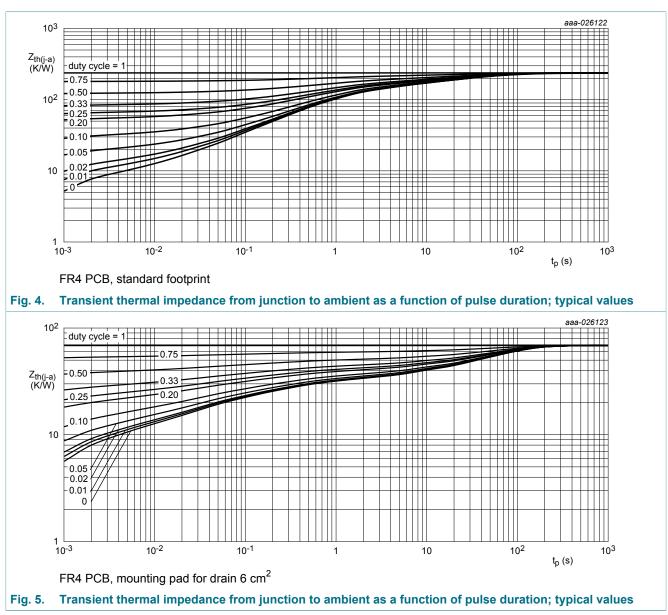


9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance	in free air	[1]	-	236	272	K/W
	from junction to ambient		[2]	-	67	77	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	12	15	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

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[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².

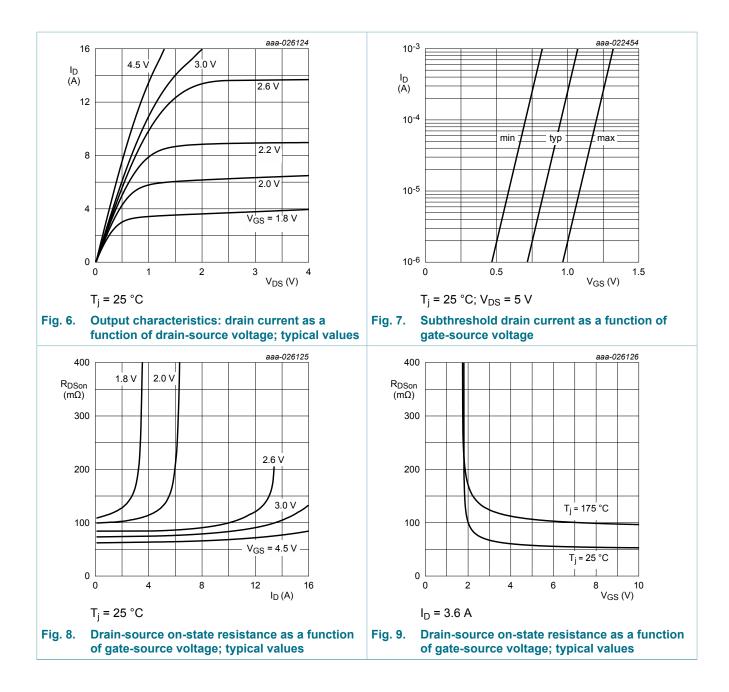
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10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics				1	
V _{(BR)DSS}	drain-source breakdown voltage	I_D = 250 µA; V_{GS} = 0 V; T_j = 25 °C	30	-	-	V
V _{GSth}	gate-source threshold voltage	$I_D = 250 \ \mu A; V_{DS} = V_{GS}; T_j = 25 \ ^{\circ}C$	0.75	1	1.25	V
I _{DSS}	drain leakage current	V _{DS} = 30 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μA
I _{GSS}	gate leakage current	V _{GS} = 12 V; V _{DS} = 0 V; T _j = 25 °C	-	-	10	μA
		V_{GS} = -12 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-10	μA
		V_{GS} = 4.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	2	μA
		V_{GS} = -4.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-2	μA
R _{DSon}	drain-source on-state	V _{GS} = 4.5 V; I _D = 3.8 A; T _j = 25 °C	-	55	72	mΩ
	resistance	V _{GS} = 4.5 V; I _D = 3.8 A; T _j = 175 °C	-	102	133	mΩ
		V _{GS} = 2.5 V; I _D = 3.1 A; T _j = 25 °C	-	77	110	mΩ
9 _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 3.8 A; T _j = 25 °C	-	20	-	S
R _G	gate resistance	f = 1 MHz	-	10.8	-	Ω
Dynamic cł	naracteristics					
Q _{G(tot)}	total gate charge	V_{DS} = 15 V; I _D = 3.6 A; V _{GS} = 4.5 V;	-	3	5	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	0.5	-	nC
Q _{GD}	gate-drain charge		-	0.9	-	nC
C _{iss}	input capacitance	V _{DS} = 15 V; f = 1 MHz; V _{GS} = 0 V;	-	255	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	31	-	pF
C _{rss}	reverse transfer capacitance		-	23	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 15 V; I _D = 3.6 A; V _{GS} = 4.5 V;	-	7	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	20	-	ns
t _{d(off)}	turn-off delay time	1	-	18	-	ns
t _f	fall time		-	8	-	ns
Source-dra	in diode	· · ·				
V _{SD}	source-drain voltage	I _S = 1.9 A; V _{GS} = 0 V; T _j = 25 °C	-	0.8	1.2	V
t _{rr}	reverse recovery time	$I_{\rm S}$ = 2.5 A; dI _S /dt = -100 A/µs;	-	12.6	-	ns
Qr	recovered charge	V _{GS} = 0 V; V _{DS} = 10 V; T _j = 25 °C	-	4	-	nC

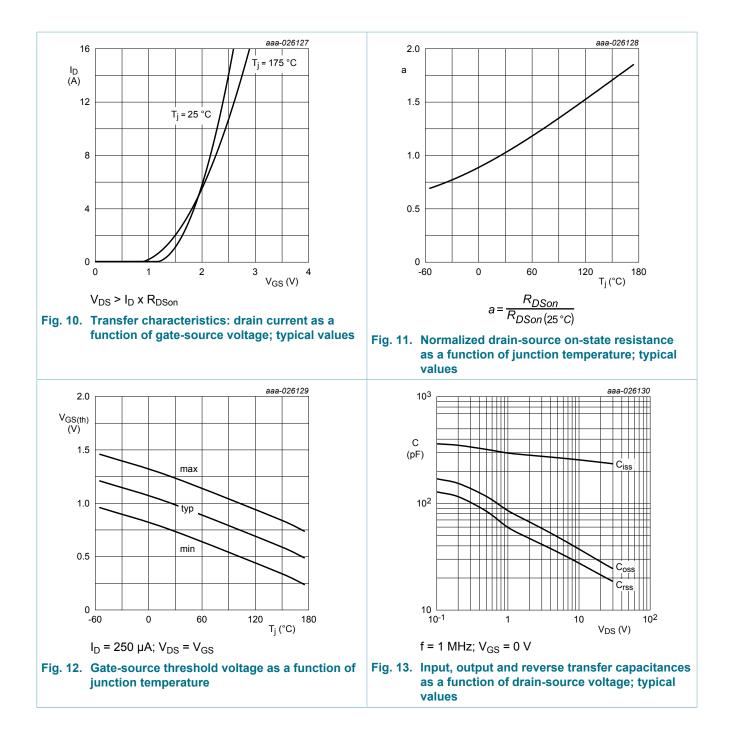
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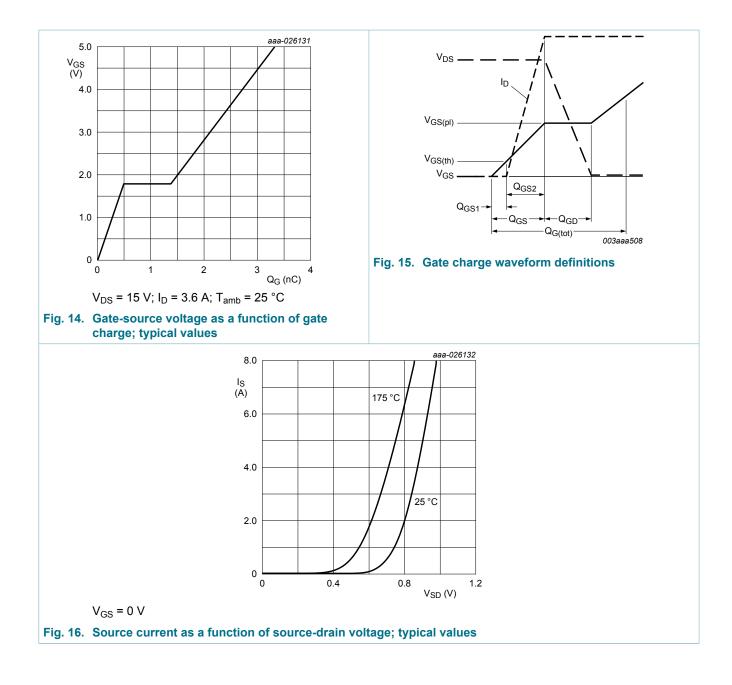
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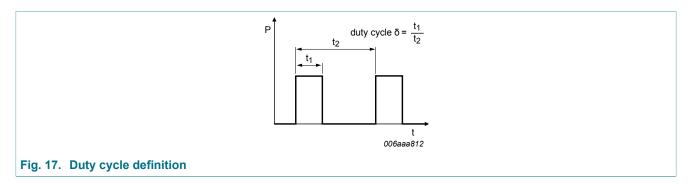
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11. Test information



Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

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12. Package outline

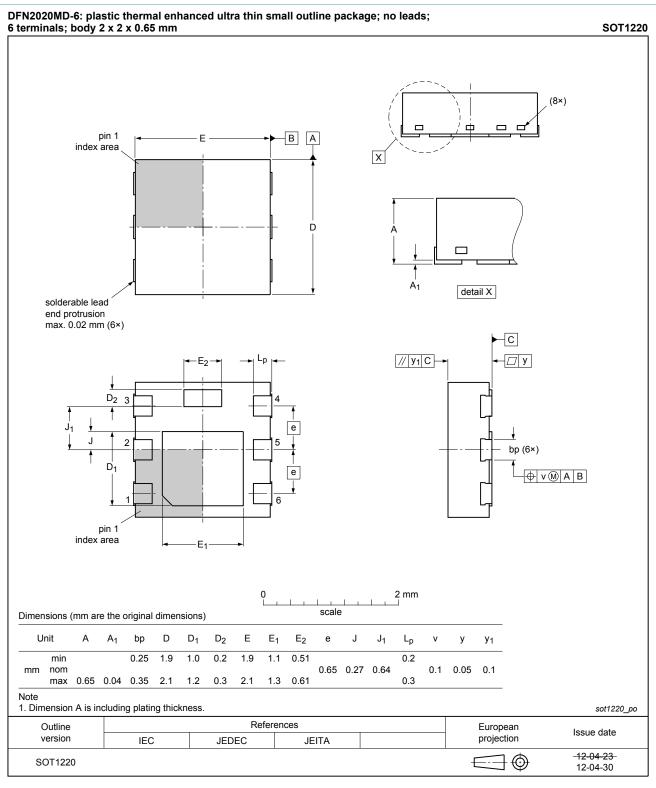
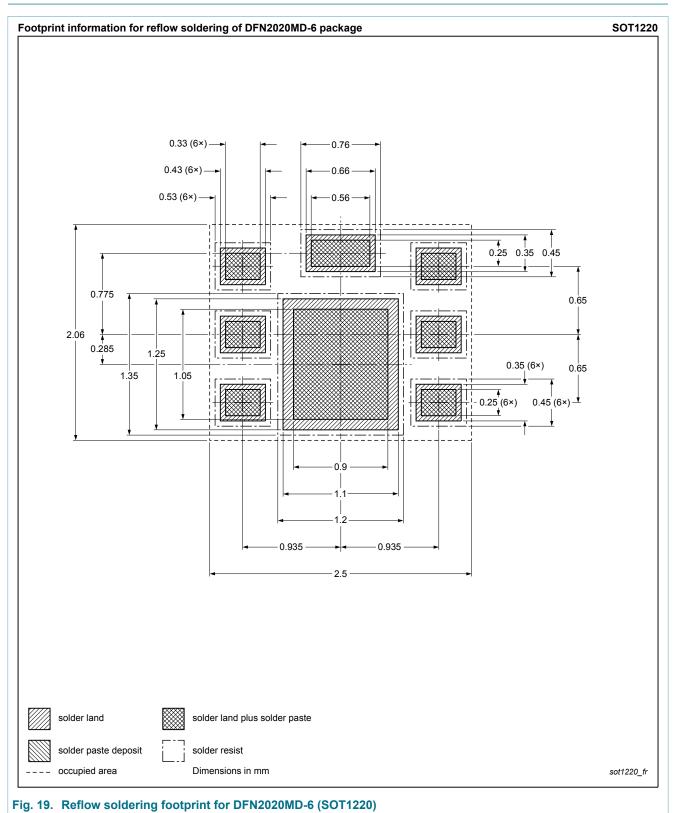


Fig. 18. Package outline DFN2020MD-6 (SOT1220)

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13. Soldering



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12 / 15

14. Revision history

Table 8. Revision history							
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PMPB55XNEA v.2	20170329	Product data sheet	-	PMPB55XNEA v.1			
Modifications>	Marking code corrected						
PMPB55XNEA v.1	20170222	Product data sheet	-	-			

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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30 V, N-channel Trench MOSFET

16. Contents

1.	General description	1
2.	Features and benefits	. 1
3.	Applications	. 1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Marking	2
8.	Limiting values	. 3
9.	Thermal characteristics	. 4
10.	Characteristics	6
11.	. Test information	10
12.	Package outline	11
13.	Soldering	12
14.	Revision history	13
15.	Legal information	14

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